

## **FJN5471**

## For Output Amplifier of Electronic Flash Unit

- High DC Currrent Gain
- Low Collector-Emitter Saturation Voltage
- High Performance at Low Supply Voltage



## **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
$V_{CEO}$	Collector-Emitter Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current	5	Α
P <sub>C</sub>	Collector Dissipation	0.75	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Voltage	$I_C=1$ mA, $I_B=0$	20			V
BV <sub>EBO</sub>	Emitter Base Voltage	I <sub>C</sub> =100μA, I <sub>C</sub> =0	7			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =10V, $I_E$ =0			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =7V, $I_{C}$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE}=2V, I_{C}=0.5A$	700	1000		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =3A, I <sub>B</sub> =0.1A			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =3A, I <sub>B</sub> =0.1A			1.5	V
f <sub>T</sub>	Current Gain Band Width Product	$V_{CE}$ =6V, $I_{C}$ =50mA		150		MHz
C <sub>ob</sub>	Collector Output Capacitance	V <sub>CB</sub> =20V, I <sub>E</sub> =0, f=1MHz		25		pF

### Thermal Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Max	Units	
$R_{\theta jA}$	Thermal Resistance, Junction to Ambient	ction to Ambient 165 °C/W		

# **Typical Characteristics**

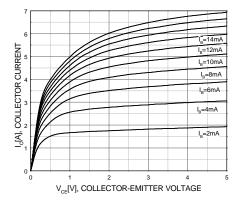


Figure 1. Static Characteristic

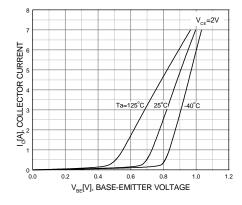


Figure 2. Base-Emitter On Voltage

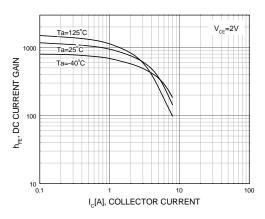


Figure 3. DC current Gain

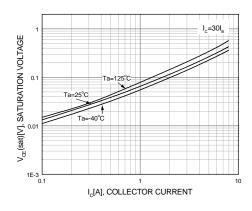


Figure 4. Collector-Emitter Saturation Voltage

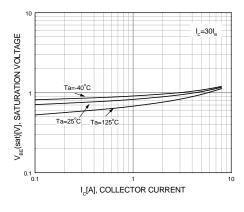


Figure 5. Base-Emitter On Voltage

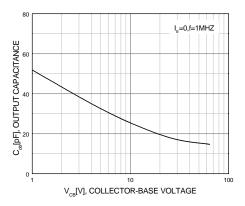


Figure 6. Collector Output Capacitance

# Typical Characteristics (Continued)

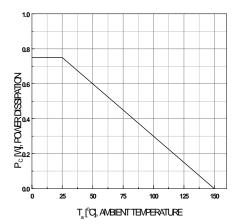
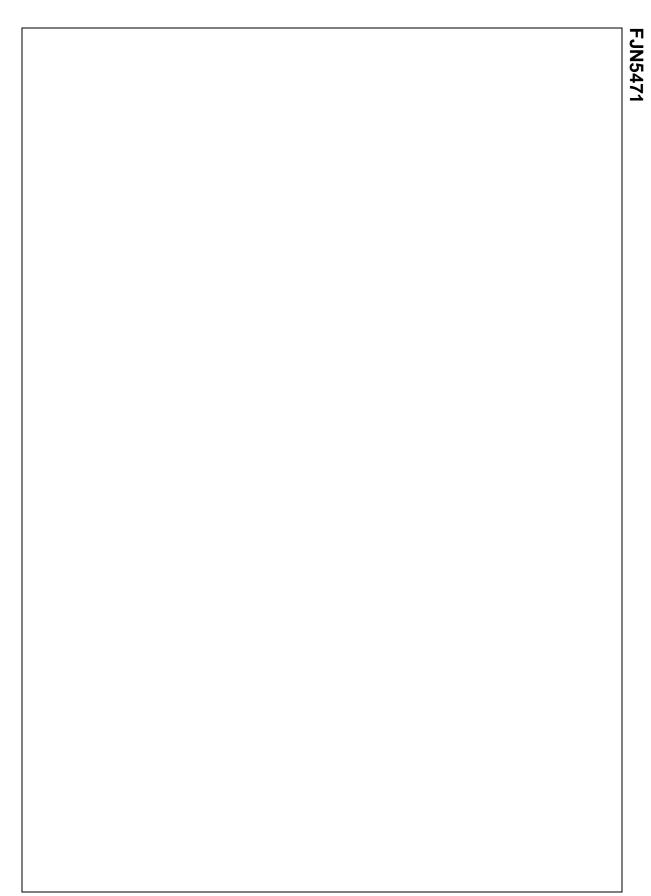
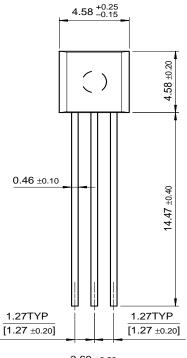


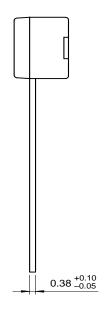
Figure 7. Power Derating

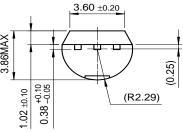


## **Package Dimensions**

TO-92







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EnSigna™	I <sup>2</sup> C™	OCXTM	RapidConfigure™	UHC™
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